



Product data sheet

1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a TO220 plastic package intended for use in applications requiring good bidirectional blocking voltage capability and high thermal cycling performance.

2. Features and benefits

- · Good bidirectional blocking voltage capability
- High thermal cycling performance

3. Applications

- Ignition circuits
- Motor control
- Protection circuits
- Voltage regulation

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	-	800	V
V_{RRM}	repetitive peak reverse voltage		-	-	800	V
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig. 4; Fig. 5	-	-	100	А
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms	-	-	110	А
T _j	junction temperature		-	-	125	°C
$I_{T(AV)}$	average on-state current	half sine wave; T _{mb} ≤ 109 °C; <u>Fig. 1</u>	-	-	7.5	A
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 109 °C; <u>Fig. 2</u> ; <u>Fig. 3</u>	-	-	12	А
Static ch	aracteristics	· ·				
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>	-	2	15	mA
Dynamic	characteristics	· ·				
dV _D /dt	rate of rise of off-state voltage	$ V_{\text{DM}} = 536 \text{ V}; \text{T}_{\text{j}} = 125 ^{\circ}\text{C}; \text{R}_{\text{GK}} = 100 \Omega; \\ (\text{V}_{\text{DM}} = 67\% \text{ of } \text{V}_{\text{DRM}}); \text{ exponential} \\ waveform; \text{Fig. 12} $	200	1000	-	V/µs
				1	1	

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	
2	A	anode	1 204	А Ӈ К
3	G	gate		G sym037
mb	A	mounting base; connected to anode		

6. Ordering information

Table 3. Ordering information								
Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
	name		method	quantity	version	issue date		
BT151-800C	TO220	BT151-800C,127	Tube	50	SOT78	13-Jun-2008		

7. Marking

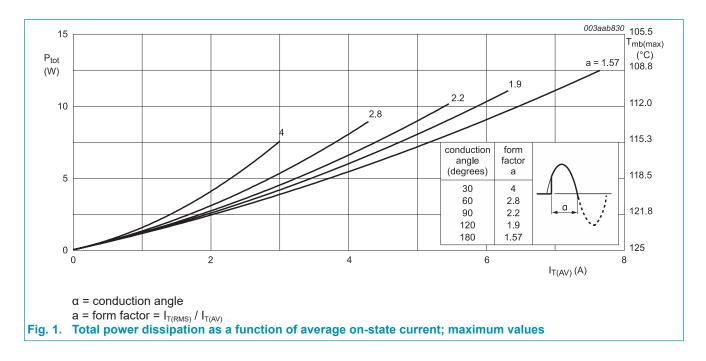
Table 4. Marking codes Type number Marking codes Assembly factory: d Assembly factory: A BT151-800C BT151 BT151 B00C B00C B00C PJdxxxx xx PJAxxxx xx

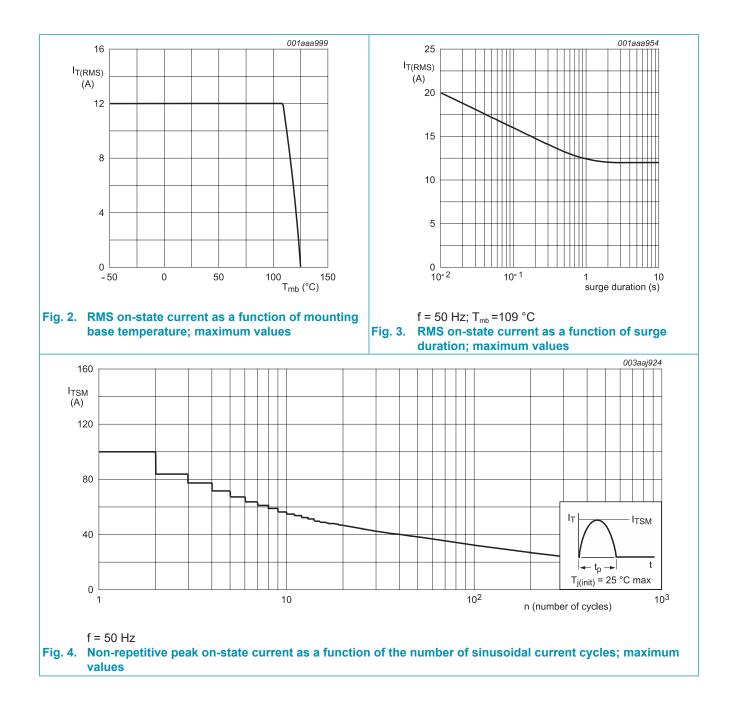
8. Limiting values

Table 5. Limiting values

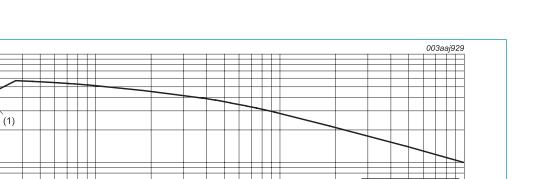
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	800	V
V_{RRM}	repetitive peak reverse voltage		-	800	V
I _{T(AV)}	average on-state current	half sine wave; $T_{mb} \le 109 \text{ °C}$; Fig. 1	-	7.5	А
I _{T(RMS)}	RMS on-state current	half sine wave; $T_{mb} \le 109 \text{ °C}$; Fig. 2; Fig. 3	-	12	А
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig. 4; Fig. 5	-	100	A
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms	-	110	А
l ² t	l ² t for fusing	t _p = 10 ms; SIN	-	50	A ² s
dl _T /dt	rate of rise of on-state current	I _G = 30 mA	-	50	A/µs
I _{GM}	peak gate current		-	2	А
V _{RGM}	peak reverse gate voltage		-	5	V
P_{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
T _i	junction temperature		-	125	°C



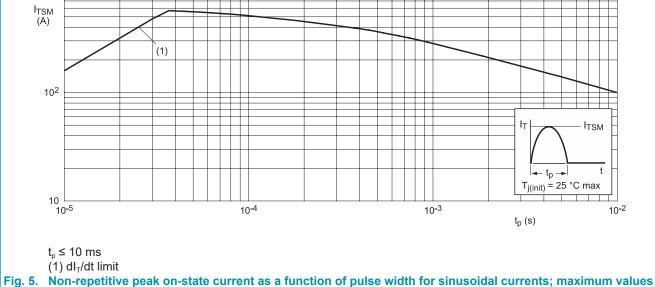


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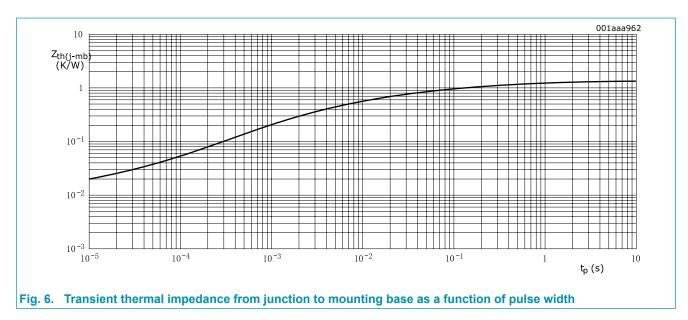
BT151-800C

SCR



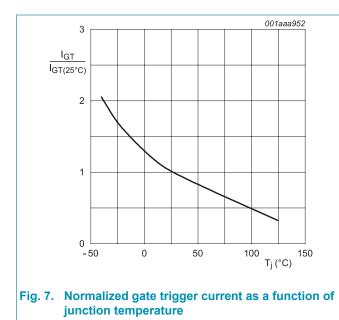
9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<u>Fig. 6</u>	-	-	1.3	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W



10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
I _{GT}	gate trigger current	$V_{\rm D}$ = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>	-	2	15	mA
I _L	latching current	$V_{\rm D}$ = 12 V; I _G = 0.1 A; T _j = 25 °C; Fig. 8	-	10	40	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	7	20	mA
V _T	on-state voltage	I _T = 23 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.44	1.75	V
V_{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 11</u>	-	0.6	1.5	V
		V _D = 500V; I _T = 0.1 A; T _j = 125 °C	0.25	0.4	-	V
I _D	off-state current	V _D = 500 V; T _j = 125 °C	-	0.1	0.5	mA
I _R	reverse current	V _R = 500 V; T _j = 125 °C	-	0.1	0.5	mA
Dynamic	characteristics	-			1	
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; R _{GK} = 100 Ω; (V _{DM} = 67% of V _{DRM}); exponential waveform; Fig. 12	200	1000	-	V/µs
		V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 12	50	130	-	V/µs
t _{gt}	gate-controlled turn-on time	$ I_{TM} = 40 \text{ A}; V_{\text{D}} = 500 \text{V}; I_{\text{G}} = 0.1 \text{A}; \\ dI_{\text{G}}/dt = 5 \text{A}/\mu\text{s}; T_{\text{J}} = 25 ^{\circ}\text{C} $	-	2	-	μs
t _q	commutated turn-off time		-	70	-	μs



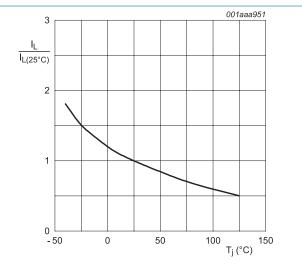
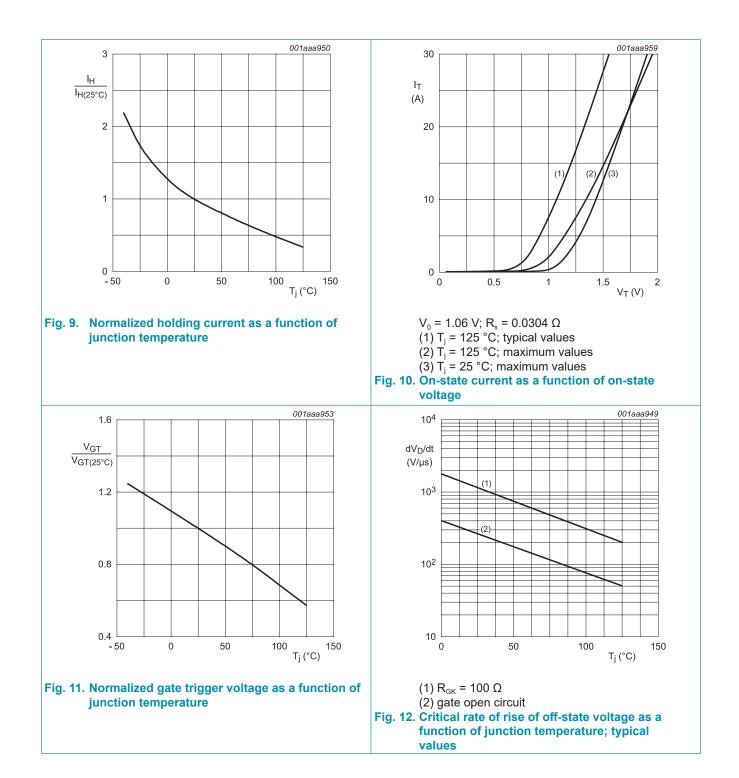
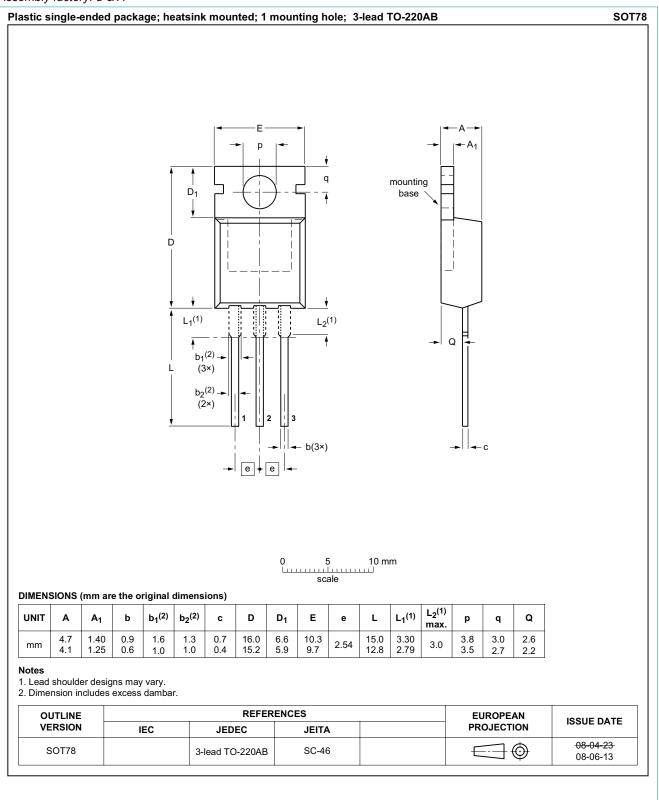


Fig. 8. Normalized latching current as a function of junction temperature



11. Package outline

Assembly factory: d & A



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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